

Technical Data Data Sheet N1810, Rev. A **Green Products** 

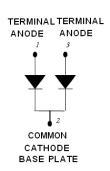
# 403CNQ600-1 ULTRAFAST RECTIFIER

## **Applications:**

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection Converters UPS System Welding

### Features:

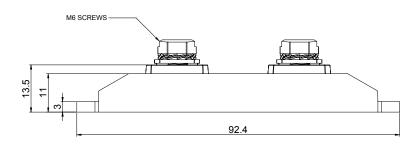
- 175 °C T<sub>J</sub> operation
- Dual Diode construction
- Low Leakage Current
- Low forward voltage drop
- High surge current capability
- Super Fast Switching
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

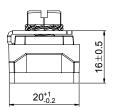


403CNQ600-1

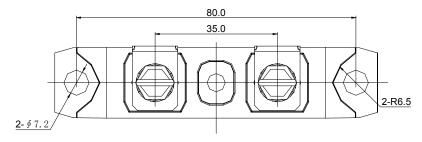
The top side is terminal, the bottom

## **Mechanical Dimensions: In mm**





side is base plate.



# PRM4-1 (Non-Isolated)

#### MARKING, MOLDING RESIN

Marking for 403CNQ600-1, 1<sup>st</sup> row SS YYWWL, 2<sup>nd</sup> row 403CNQ600-1 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin

Epoxy resin UL: 94V-0

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



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**Maximum Ratings:** 

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	600	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =125°C, rectangular wave form	400	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	2800	Α

# **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 200A, Pulse, T <sub>J</sub> = 25 °C	1.25	1.35	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated VR } T_J = 25  ^{\circ}\text{C}$	0.40	20	μA
	I <sub>R2</sub>	$@V_R = \text{rated VR } T_J = 125  ^{\circ}\text{C}$	-	3	mΑ
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	146	180	ns

 $<sup>^{\</sup>star}\,$  Pulse Width < 300  $\mu s$ , Duty Cycle <2%

**Thermal-Mechanical Specifications:** 

Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	$T_J$	-	-55 to +175	°C	
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C	
Typical Thermal Resistance Junction to Case(per diodes)	$R_{ heta JC}$	DC operation	0.14	°C/W	
Approximate Weight	wt	-	80	g	
Mounting torque	$T_M$	-	30(3.4)	Lbf.in	
Mounting torque			18(2.1)	(N.M)	
Terminal torque			30(3.4)		
Case Style	PRM4-1(Non-Isolated)				

<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •





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